

SLE 66C24PE Short Product Information Ref.: SPI_SLE 66C24PE_010			
This document contains preliminary information on a new product under development. Details are subject to change without notice.			
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Important.	Further information is confidential and on request. Please contact: Infineon Technologies AG in Munich, Germany,
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Edition 2005

Published by Infineon Technologies AG, CC Applications Group St.-Martin-Strasse 53, D-81541 München © Infineon Technologies AG 2002 All Rights Reserved.

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We hereby disclaim any and all warranties, including but not limited to warranties of non-infringement, regarding circuits, descriptions and charts stated herein.

Infineon Technologies is an approved CECC manufacturer.

Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office in Germany or our Infineon Technologies Representatives world-wide (see address list).

Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.



8/16-Bit Security Controller with enhanced instruction set for large memories in 0.22µm CMOS Technology, 68-Kbyte ROM, 2304 Bytes RAM, 2-Kbyte EEPROM and Dual Key Triple DES Accelerator

Features

- 8/16-bit microcomputer in 0.22 µm CMOS technology
- Instruction set opcode compatible with standard SAB 8051 processor
- Downward compatibility to existing SLE 66CxxxP products for existing masks without using the new features
- Addressable memory up to 16 Mbyte
- Additional enhanced instructions for direct physical memory access of >64kByte
 - Typically saves up to 90 % code space and increases execution speed up to 80 %
 - Dedicated, non-standard architecture with execution time 6 times faster than standard SAB 8051 processor at same external clock. (Up to 18 times faster using internal frequency PLL x 3 compared to external clock).
 - 68 Kbytes User ROM for application programs
 - 2 Kbytes MicroSlim-EEPROM
 - 2Kbytes XRAM, 256 bytes internal RAM
 - Enhanced Memory Management and Protection Unit (MMU) with application and user defined segments
 - Dual Key Triple DES (DDES)
 - CC EAL5+ certification according to BSI-PP-0002 planned
 - True Random Number Generator with Firmware test function
 - CRC Module
 - 16-bit Interrupt Module
 - Code executions during E²-programming for faster personalization
 - EEPROM programming voltage generated on chip



 Internal Clock with up to 33 MHz: Programmable internal frequency (PLL x1, x2, x3, x4 and free running mode(s)).

Adjustable internal frequency according to

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- available power or required performance
 Increased internal clock frequency for maximum
- Internal frequency is automatically adjusted to guarantee a given limited power consumption
- Two 16-bit Autoreload Timer
- Power saving sleep mode

performance

- Ext. Clock freq. 1 up to 7.5 MHz for int. Clock up to 33 MHz
- UART for handling serial interface in accordance with ISO/IEC 7816 part 3 supporting transmission protocols T=1 and T=0
- Supply voltage range:1.8 V, 3.0 V, 5.0 V
- Support of current consumption limits by GSM / UICC applications
 - < 10 mA @ 5.5 V
 - < 6 mA @ 3.3 V < 4 mA @ 1.98 V
- Operating Temperature range: -25 to +85°C
- Storing temperature range: -40° to +125°C
- ESD protection larger than 6 kV (HBM)

MicroSlim-EEPROM

- Write cycle time 0.7ms
- Erase cycle time 0.7 ms
- Typical programming time (erase & write) incl. firmware 2 ms
- Fast personalization mode < 0.9 ms per page
- Enhanced Error Correction Unit controlled by OS
- Reading and programming byte by byte
- Flexible page mode for 1 to 64 bytes write/erase operation
- 32 bytes security area (OTP)
- Minimum of 500.000 write/erase cycles @ 25°C per page. Maximum of 16.500.000 write/erase cycles per sector
- Typical data retention of 10 years @ 25°C

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Memory Management and Protection Unit



- Addressable memory of up to 16 Mbyte
 - Separates OS (system mode) and application (user mode)
 - System routines called by interrupts
 - OS can restrict access to peripherals in application mode
 - Variable application orientated segments defined and controlled by OS
 - Code execution from XRAM possible
- Enhanced multi-application support by 16 descriptors for system / application mode.

Security Features

- Enhanced sensor concept:
 - Low and high voltage sensors
 - Frequency sensors and filters
 - Light Sensor
 - Glitch Sensors
 - Temperature Sensor
 - Life Test Function for Sensors (UMSLC)
- Bus confusion
- Security reset detection
- Current control oscillator (ICO)

Memory Security

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Sparkling SFR encryption for DDES and ACE, CRC module and RNG

- 32 bytes security PROM, hardware protected for batch-, wafer-, die-individual security data. Unique chip identification number for each chip
- Additional memory for customer-defined security FabKey on request
- MED memory encryption/decryption device for XRAM, ROM and EEPROM
- Security optimized layout and layout scrambling
- Fast IRAM erase
- Enhanced Error correction unit (ECU)

Testmode

Irreversible Lock - Out of test-mode

Anti Snooping

- Automatic randomization smoothing of power profile
- Effective HW-countermeasures against SEMA/DEMA, SPA/DPA, DFA and Timing-Attacks
- Non standard dedicated Smart Card CPU Core
- Active Shield with automatic and user controlled attack detection
- Hardware countermeasures controlled by True Random Number Generator

Targeted Certification

- CC EAL5+
- VISA level 3
- CAST

Support

- HW-& SW-Tools (Emulator, ROM Monitor, Card Emulator, Simulator, Softmasking)
- Application notes

Supported Standards

- ISO/IEC 7816
- EMV 2000
- GSM 11.11, 11.12, 11.18
- ETSI TS 102 221

Document References

- Confidential Data Book SLE 66CxxxPE
- Qualification report
- Chip delivery specification for wafer with chip-layout (die size, orientation,...)
- Module specification containing description of package, etc.
- Qualification report module

Development Tools Overview

- Short Product Information Software Development Kit SDK CC
- Short Product Information ROM Monitor RM66PE
- Short Product Information Emulator ET66PE Hitex or ET66PE KSC
- Short Product Information Smart Mask Package



Performance DDES- Accelerator (typical values, based on internal test results)

Operation			Encryption Time for an 8-Byte Block incl. Data Transfer		
		5 MHz	15 MHz	33 MHz*	
56-bit Single DES Encryption	64 bit	23 µs	8 µs	3.5 µs	
112-bit Triple DES Encryption	64 bit	35 µs	12 µs	5.3 µs	

* preliminary values

Ordering Information

Туре	Package ¹	Voltage Range	Temperature Range	Frequency Range (int. clock frequency	Frequency Range (ext. clock frequency)
SLE 66C24P E C	Die (sawn, unsawn)	1.8 V; 3.0 V; 5.0 V	– 25°C to + 70°C	Up to 33 MHz	1 MHz - 5 MHz
SLE 66C24P E M5	M5.1	or 3.0 V; 5.0 V	or – 25°C to + 85°C		or 1 MHz - 7.5 MHz

For ordering information please refer to the databook and contact your sales representative.

¹ available as wire-bonded module (M5) for embedding in plastic cards or as die (C) for customer packaging



Pin Configuration

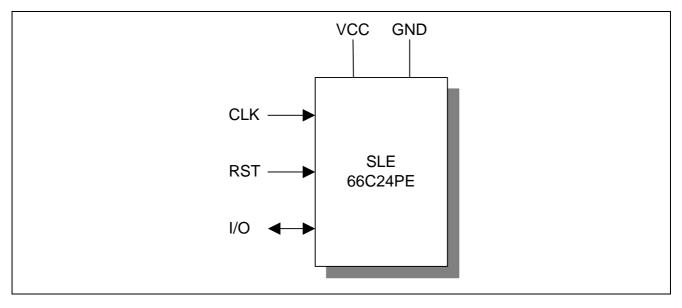


Figure 1: Pin Configuration

Pin Definitions and Functions

Symbol	Function
VCC	Operating voltage
RST	Reset input
CLK	Processor clock input
GND	Ground
I/O	Bi-directional data port



General Description

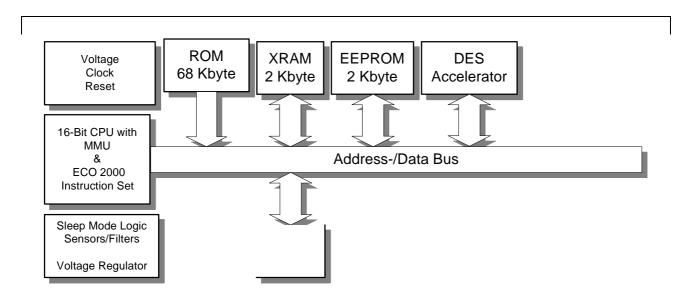
The SLE66C24PE is a member of the improved 66PE-series of Infineon Technologies. This high performance security controller is manufactured in advanced 0.22 µm CMOS technology. It is downward compatible to existing 66P controller derivatives. The well known ECO2000 8/16 bit CPU provides the high efficiency of the SAB 8051 instruction set extended by additional powerful instructions together with enhanced performance, memory sizes and security features compared to existing 66P derivatives.

Performance: The internal clock frequency can be adjusted to a level up to 33 MHz either as a multiple of 1,2,3,4 to the external frequency or independent of the clock rate of the terminal with the help of the internal clock. It is adjustable according to either available power requirements or required performance:

- Increased internal clock frequency for maximum performance, e.g. for high performance with max. frequency in payment applications.
- Automatically adjusted frequency for a max. given power consumption, e.g. by GSM or UMTS requirements.

Memory: The SLE66C24PE offers 68 Kbytes of User-ROM, 256 Bytes internal RAM, 2048 byte XRAM and 2 Kbytes MicroSlim-EEPROM, to fulfill the requirements of mainly SDA payment, Identification and loyalty applications. The large ROM size allows to place applications in the ROM-mask and to keep the E²PROM free for customer data. In addition it saves mask development costs, as one mask may be used for different customer projects.

The enhanced Memory Management and Protection Unit allows a secure separation of the operating system and different applications. It allows to separate the memories in application orientated segments, which can be controlled by the OS. Furthermore, the MMU makes a secure downloading of applications possible even after personalization of a card. These new features suit the requirements of the next generation of multi application operating systems.





Security features:

Since the very beginning, security is an integrated part of Infineons product development, as proved by various certificates (ITSEC, CC, Proton, VISA, ZKA, Mondex). The so called "**integral security concept**" for the 66P series ensures:

- A secret storage of any confidential code, data and keys
- Protection against side channel attacks such as: Simple Power Analysis (SPA), Differential Power Analysis (DPA),
- Protection against Differential Fault Analysis (DFA), Electromagnetic Emanation Attack (EMA) and other possible HW or SW attacks

Peripherals: The CRC module allows the easy generation of checksums according to ISO/IEC 3309 (16-Bit-CRC). To minimize the overall power consumption, the chip card controller IC offers a sleep mode. The UART supports the half-duplex transmission protocols T=0 and T=1 according to ISO/IEC 7816-3. All relevant transmission parameters can be adjusted by software, as e.g. the clock division factor, direct/inverse convention and the number of stop bits. Additionally, the I/O port can be driven by communication routines realized in software.

The HW-DES module supports symmetric crypto algorithms according to the Data Encryption Standard in the Electronic Code Book Mode.

The random number generator (RNG) is able to supply the CPU with true random numbers on all conditions.

The advanced sensor concept includes various sensors for any kind of attack scenarios and even more important a "Life Test " for sensors.

As an important feature, the chip provides an on-chip security, which fulfills the strong security requirements of a Common Criteria evaluation at an EAL5+ level.

In conclusion, the SLE 66C24PE fulfills all the requirements of today's chip card applications, and is especially designed for SDA payment and loyalty applications. In addition it offers a powerful platform for multi application cards based on Multos, Java or WinSC.

The SLE66C24PE offers additional peripherals, in combination with enhanced performance and optimized power consumption on a minimized die size.